500 mA High Side (PNP) Driver with On-Chip Flyback Diode

The CS8240 is a fast, PNP high side driver capable of delivering up to 500 mA into a resistive or inductive load in harsh automotive or industrial environments. An internal flyback diode clamp is incorporated for inductive loads. The input (V_{IN}) is TTL and CMOS compatible and has hysteresis to minimize the effects of noise. When the input is high, the output is on. When the input is low, the output is off and the supply voltage quiescent current is very low (< 1.0 µA, typ). For device protection, the CS8240 incorporates thermal shutdown, short circuit current limiting, overvoltage shutdown, and reverse battery protection. The CS8240 can withstand supply voltage transients of 60 V (min) and -50 V.

The CS8240 is available in an overmolded 5 lead TO-220 package and is a competitive replacement for the LM-1921, LM-1951, LM-1952, MC-3399, and L-9350.

Features

- Low Output Saturation Voltage
 - 0.22 V at I_{OUT} = 125 mA
 - 0.33 V at I_{OUT} = 225 mA
- Overmolded Package
- On-Chip Flyback Diode
- Fault Protection
 - Over Voltage Shutdown (32 V, typ)
 - Thermal Shutdown (165°C, typ)
 - Short Circuit Limiting (1.1 A typ)
 - -50 V Reverse Transient Protection
 - 60 V Load Dump Protection
 - Reverse Battery
- Low Quiescent Current (Off State)
- ESD Protected



Figure 1. Block Diagram



ON Semiconductor[™]

http://onsemi.com





VWV, W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
CS8240YTQ5	TO–220 FIVE LEAD STRAIGHT	50 Units/Rail
CS8240YTQVA5	TO-220 FIVE LEAD VERTICAL	50 Units/Rail

MAXIMUM RATINGS*

Ratin	g	Value	Unit
Supply Voltage		6.0 to 26	V
Overvoltage Protection		60	V
Reverse Voltage:	DC Transient	-16 -50	V V
Internal Power Dissipation		Internally limited	-
Logic Input Voltage		-0.3 to +7.0	V
Junction Temperature Range, T_J		-40 to150	°C
Storage Temperature Range, T _S		–55 to +165	°C
Lead Temperature Soldering:	Wave Solder (through hole styles only) (Note 1)	260 peak	°C
Electrostatic Discharge (Human Body Model)		2.0	kV

1. 10 second maximum.

*The maximum package power dissipation must be observed.

$\label{eq:expectation} \textbf{ELECTRICAL CHARACTERISTICS} \quad (-40^{\circ}C \leq T_A \leq 125^{\circ}C; -40^{\circ}C \leq T_J \leq 150^{\circ}C, \text{ unless otherwise specified.})$

Characteristic	Test Conditions	Min	Тур	Max	Unit
General Characteristics	·				
Operating Supply Voltage	-		_	_	V
Quiescent Current		-	1.0	100	μA
	$6.0 \text{ V} \le \text{V}_{CC} \le 20 \text{ V}$	-	16	30	mA
	$20 \text{ V} \le \text{V}_{\text{CC}} \le 24 \text{ V}$	—	25	50	mA
Output Stage				•	
Output Saturation Voltage	$V_{IN} \le V_{IN(HI)}, V_{CC} = 6.0 \text{ V}, I_{LOAD} = 125 \text{ mA}$	-	0.22	0.5	V
	$V_{CC} = 14 \text{ V}, \text{ I}_{LOAD} = 225 \text{ mA}$	-	0.33	0.7	V
Output Leakage Current	Input \leq V _{IN(L)} , V _{CC} = 12 V, V _{OUT} = 0 V	-	1.0	150	μA
Negative Output Clamp	I _{CLAMP} = 100 mA, V _{CC} = 12 V	-18	-15.5	-12	V
Turn On Delay Time	V _{CC} = 12 V, I _{LOAD} = 150 mA	-	5.0	20	μs
Turn Off Delay Time	V _{CC} = 12 V, I _{LOAD} = 150 mA	-	5.0	20	μs
Input Stage					
Input Voltage	Logic = High, V_{CC} = 12 V Turn ON	0.8	1.45 1.2	-	V
	Logic = Low, V _{CC} = 12 V Turn OFF	-	1.2	2.0	v
Input Current	V _{IN} = 5.5 V	-	100	200	μA
	V _{IN} = 0.8 V	-	15	50	μA
Protection Circuitry					
Overvoltage Shutdown	$V_{IN} \ge V_{IN(HI)}$	26	32	-	V
Output Short Circuit Current	$V_{IN} \ge V_{IN(HI)}, V_{CC} = 12 \text{ V}, V_{OUT} = 0 \text{ V}$	0.55	1.1	2.5	А
Thermal Shutdown	-	150	165	_	°C

PACKAGE PIN DESCRIPTION

PACKAGE PIN #		
5 Lead TO-220	PIN SYMBOL	FUNCTION
1	V _{CC}	Supply Voltage to the IC. Supplies load current through PNP.
2	OUT	Collector of output PNP, current to load is sourced from this lead.
3	NC	No connection.
4	GND	Ground.
5	V _{IN}	Input voltage to control output. Logic high turns output on. Logic low turns output off.

TYPICAL PERFORMANCE CHARACTERISTICS





Figure 5. Output Saturation Voltage vs. $\mathsf{I}_{\mathsf{OUT}}$



CIRCUIT DESCRIPTION

Input Stage

The input stage is a self biased band gap based circuit with a positive going trip point of 1.45 V (typ) and a negative going trip point of 1.20 V (typ) (250 mV of hysteresis). When the input voltage is below the positive trip point, the quiescent current of the supply voltage line is less than 1.0 μ A, (typ). When the input voltage exceeds the positive trip point (1.45 V, typ), the input stage "wakes up" the rest of the CS8240 circuitry and turns on the output stage.

Output Stage

The output stage is built around a high current PNP output transistor. A control amplifier monitors the saturation voltage of the output PNP and maintains a balance of low saturation voltage and minimum base drive to the PNP for the given output current. The base drive of the PNP is the dominant component of the quiescent current of the CS8240 and is dependent on the level of output current.

Short circuit protection (1.1 A, typ) is also incorporated in the output stage.

Protection Circuitry

In addition to the short circuit protection mentioned above, the CS8240 also incorporates a thermal shutdown circuit (165°C, typ) and a high voltage shutdown circuit (33 V, typ), both of which cut off the drive to the PNP output transistor when excessive current is drawn. Inherent in the design of the CS8240 is transient protection to +60 V and -50 V on the supply line. The CS8240 is ESD protected in excess of 2.0 kV (Human Body Model).

CS8240

TYPICAL APPLICATION CIRCUITS







Figure 9. Lamp Driver



Figure 10. Controlled High Side Switch

PACKAGE THERMAL DATA

Parameter		TO–220, Five Lead	Unit
R _{OJC}	Typical	4.0	°C/W
R _{OJA}	Typical	50	°C/W